DATA SHEET



BIPOLAR ANALOG INTEGRATED CIRCUITS μ PC2757TB, μ PC2758TB

SILICON MMIC 1st FREQUENCY DOWN-CONVERTER FOR CELLULAR/CORDLESS TELEPHONE

DESCRIPTION

The μ PC2757TB and μ PC2758TB are silicon monolithic integrated circuit designed as 1st frequency downconverter for cellular/cordless telephone receiver stage. The ICs consist of mixer and local amplifier. The μ PC2757TB features low current consumption and the μ PC2758TB features improved intermodulation. From these two version, you can chose either IC corresponding to your system design. These TB suffix ICs which are smaller package than conventional T suffix ICs contribute to reduce your system size.

The μ PC2757TB and μ PC2758TB are manufactured using Renesas 20 GHz fr NESAT^MIII silicon bipolar process. This process uses silicon nitride passivation film and gold electrodes. These materials can protect chip surface from external pollution and prevent corrosion/migration. Thus, this IC has excellent performance, uniformity and reliability.

FEATURES

- Wideband operation : fRFin = 0.1 to 2.0 GHz, fIFout = 20 to 300 MHz
 - High-density surface mounting : 6-pin super minimold package
- Low current consumption
- : Icc = 5.6 mA TYP. @ μPC2757TB Icc = 11 mA TYP. @ μPC2758TB
- Supply voltage
- : Vcc = 2.7 to 3.3 V
- Minimized carrier leakage
- Due to double balanced mixerSingle-end push-pull IF amplifier
- Equable output impedance
- Built-in power save function
- APPLICATIONS
- Cellular/cordless telephone up to 2.0 GHz MAX. (example: GSM, PDC800M, PDC1.5G and so on): μPC2758TB
- Cellular/cordless telephone up to 2.0 GHz MAX. (example: CT1, CT2 and so on): μPC2757TB

ORDERING INFORMATION

Part Number	Package	Markings	Supplying Form	Product Type
μРС2757ТВ-ЕЗ	6-pin	C1X	Embossed tape 8 mm wide.	Low current consumption
μPC2758TB-E3	super minimold	C1Y	Pin 1, 2, 3 face the tape perforation side. Qty 3kpcs/reel.	High OIP ₃

Remark To order evaluation samples, please contact your nearby sales office (Part number for sample order: μ PC2757TB-A, μ PC2758TB-A).

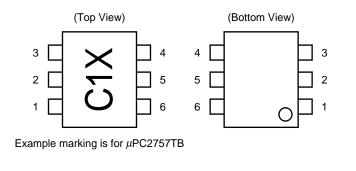
Caution Electro-static sensitive devices

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1. PIN CONNECTIONS



$\mu \text{PC2757TB},\,\mu \text{PC2758TB}$ in common

Pin No.	Pin Name	
1	RFinput	
2	GND	
3	LOinput	
4	PS	
5	Vcc	
6	IFoutput	

2. PRODUCT LINE-UP (TA = +25°C, Vcc = VPS = 3.0 V, ZS = ZL = 50 Ω)

Items Part No.	No RF Icc (mA)	900 MHz SSB · NF (dB)	1.5 GHz SSB · NF (dB)	1.9 GHz SSB · NF (dB)	900 MHz CG (dB)	1.5 GHz CG (dB)	1.9 GHz CG (dB)	900 MHz IIP ₃ (dBm)	1.5 GHz IIP ₃ (dBm)	1.9 GHz IIP₃ (dBm)
μPC2757T	5.6	10	10	13	15	15	13	-14	-14	-12
μPC2757TB	5.0	10	10	13	15	15	13	-14	-14	-12
μPC2758T	11	9	10	12	19	10	17	-13	10	11
μPC2758TB	11	9	10	13	19	18	17	-13	-12	-11
μPC8112T	0 5	9	11	11	15	13	13	10	_9	-7
μPC8112TB	8.5	Э	T1	11	15	13	13	-10	-9	-7

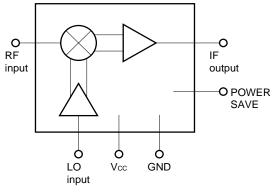
Items Part No.	900 MHz Po _(sat) (dBm)	1.5 GHz Po _(sat) (dBm)	1.9 GHz Po _(sat) (dBm)	900 MHz RFL0 (dB)	1.5 GHz RF∟o (dB)	1.9 GHz RF∟o (dB)	IF Output Configuration	Packages
μPC2757T	-3		-8					6-pin minimold
μPC2757TB	-3		-0	-	-	-		6-pin super minimold
μPC2758T	+1		-4				Emitter follower	6-pin minimold
μPC2758TB	+1		-4	-	-	_		6-pin super minimold
μPC8112T	-2.5	-3	-3	-80	-57	-55	Open collector	6-pin minimold
μPC8112TB	-2.5	-3	-3	-00	-37	-55	Open collector	6-pin super minimold

Remark Typical performance. Please refer to ELECTRICAL CHARACTERISTICS in detail.

2. This document is to be specified for μ PC2757TB, μ PC2758TB. The other part number mentioned in this document should be referred to the data sheet of each part number.

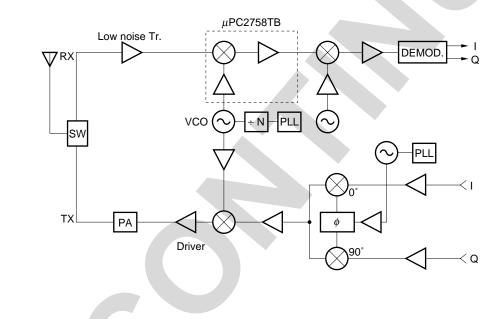
Cautions 1. The μ PC2757 and μ PC2758's IIP₃ are calculated with Δ IM₃ = 3 which is the same IM₃ inclination as μ PC8112. On the other hand, OIP₃ of Standard characteristics in page 7 is cross point IP.

3. INTERNAL BLOCK DIAGRAM (µPC2757TB, µPC2758TB in common)



4. SYSTEM APPLICATION EXAMPLE





5. PIN EXPLANATION (Both µPC2757TB, 2758TB)

Pin No.	Pin Name	Applied Voltage (V)	Pin Voltage (V) ^{Note}	Function and Application	Internal Equivalent Circuit
1	RFinput	_	1.2	This pin is RF input for mixer designed as double balance type. This circuit contributes to suppress spurious signal with minimum LO and bias power consumption. Also this symmetrical circuit can keep specified performance insensi- tive to process-condition distribution.	From Vcc LO LO To IF Amp. To IF Amp.
2	GND	GND	_	This pin is ground of IC. Must be connected to the system ground with minimum inductance. Ground pattern on the board should be formed as wide as possible. (Track length should be kept as short as possible.)	
3	LOinput		1.3	This pin is LO input for local buffer designed as differential amplifier. Recommendable input level is –15 to 0 dBm. Also this symmetrical circuit can keep specified performance insensitive to process- condition distribution.	€ Vcc Wixer 3 ↓ ↓ ↓ ↓ ↓
4	PS	Vcc or GND		This pin is for power-save function. This pin can control ON/OFF operation with bias as follows; Bias: V Operation VPs ≥ 2.5 ON 0 to 0.5 OFF Rise time/fall time using this pin are approximately 10 μ s.	
5	Vcc	2.7 to 3.3	_	Supply voltage 3.0 ± 0.3 V for operation. Must be connected bypass capacitor. (example: 1 000 pF) to minimize ground impedance.	_
6	IFoutput	_	1.7	This pin is output from IF buffer amplifier designed as single-ended push-pull type. This pin is assigned for emitter follower output with low- impedance. In the case of connecting to high-impedance stage, please attach external matching circuit.	Vcc 6

Note Each pin voltage is measured at Vcc = 3.0 V

6. ABSOLUTE MAXIMUM RATINGS

	Parameter	Symbol Conditions		Ratings	Unit	
	Supply Voltage	Vcc	Vcc TA = +25°C		V	
*	Power Dissipation of Package Allowance	PD	Mounted on $50 \times 50 \times 1.6$ mm double sided copper clad epoxy glass board at TA = +85°C	270	mW	
	Operating Ambient Temperature	TA		-40 to +85	°C	
	Storage Temperature	Tstg		-55 to +150	°C	
	PS Pin Voltage	VPS	TA = +25°C	5.5	V	

7. RECOMMENDED OPERATING RANGE

Parameter	Symbol	MIN.	TYP.	MAX.	Unit	
Supply Voltage	Vcc	2.7	3.0	3.3	V	
Operating Ambient Temperature	TA	-40	+25	+85	°C	
LO Input Power	PLOin	-15	-10	0	dBm	

8. ELECTRICAL CHARACTERISTICS (TA = +25°C, Vcc = VPs = 3.0 V, PLoin = -10 dBm, Zs = ZL = 50 Ω)

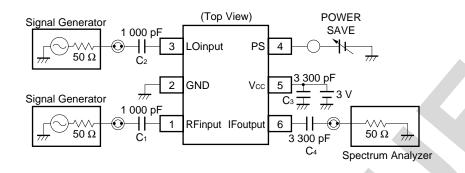
Parameter	Sumbol	Conditions	μ	PC27571	В	μ	PC27581	В	Unit	
Parameter	Symbol	Conditions	MIN. TYP. MAX.		MAX.	MIN. TYP. M		MAX.		
Circuit Current	Icc	No input signal	3.7	5.6	7.7	6.6	11	14.8	mA	
RF Input Frequency	fRFin	CG ≥ (CG1 –3 dB) fiFout = 130 MHz constant	0.1	_	2.0	0.1	_	2.0	GHz	
IF Output Frequency	fiFout	$\label{eq:cG} \begin{array}{l} CG \geq (CG1 - 3 \text{ dB}) \\ f_{\text{RFin}} = 0.8 \text{ GHz constant} \end{array}$	20	_	300	20	_	300	MHz	
Conversion Gain 1	CG1	$f_{\text{RFin}} = 0.8 \text{ GHz}, f_{\text{IFout}} = 130 \text{ MHz}$ $P_{\text{RFin}} = -40 \text{ dBm}, \text{ Upper local}$	12	15	18	16	19	22	dB	
Conversion Gain 2	CG2	$\label{eq:result} \begin{array}{l} f_{\text{RFin}} = 2.0 \text{ GHz}, \ f_{\text{IFout}} = 250 \text{ MHz} \\ P_{\text{RFin}} = -\!$	10	13	16	14	17	20	dB	
SSB Noise Figure 1	SSB • NF1	f _{RFin} = 0.8 GHz, f _{IFout} = 130 MHz, SSB mode, Upper local	_	10	13	-	9	12	dB	
SSB Noise Figure 2	SSB • NF2	$f_{\text{RFin}} = 2.0 \text{ GHz}, f_{\text{IFout}} = 250 \text{ MHz},$ SSB mode, Lower local	_	13	16	_	13	15	dB	
Saturated Output Power 1	Po(sat) 1	$\label{eq:result} \begin{array}{l} f_{\text{RFin}} = 0.8 \text{ GHz}, f_{\text{IFout}} = 130 \text{ MHz} \\ P_{\text{RFin}} = -10 \text{ dBm}, \text{ Upper local} \end{array}$	-11	-3	-	-7	+1	_	dBm	
Saturated Output Power 2	Po(sat) 2	$\label{eq:result} \begin{split} f_{\text{RFin}} &= 2.0 \text{ GHz}, \text{ f}_{\text{Fout}} = 250 \text{ MHz} \\ P_{\text{RFin}} &= -10 \text{ dBm}, \text{ Lower local} \end{split}$	-11	-8	_	-7	-4	_	dBm	

9. STANDARD CHARACTERISTICS FOR REFERENCE (Unless otherwise specified: T_A = +25°C, V_{CC} = V_{PS} = 3.0 V, P_{LOin} = -10 dBm, Z_S = Z_L = 50 Ω)

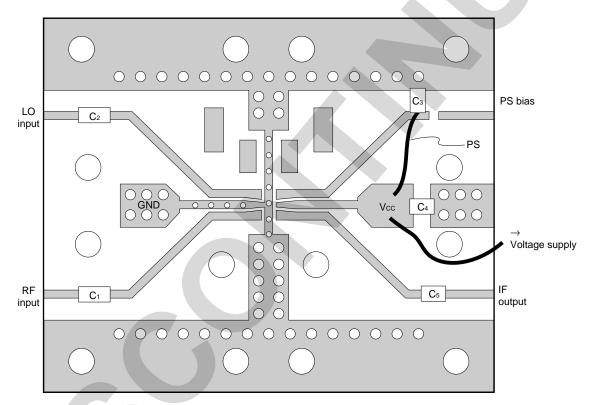
Devenueter	Currente e l			Reference Value			
Parameter	Symbol	Conditions	μРС2757ТВ μРС2758ТВ		Unit		
3rd Order Distortion Output Intercept Point	OIP₃	$f_{RFin} = 0.8$ to 2.0 GHz, $f_{IFout} = 0.1$ GHz, Cross point IP	+5	+11	dBm		
LO Leakage at RF pin	LOrf	fLOin = 0.8 to 2.0 GHz	-35	-30	dBm		
LO Leakage at IF pin	LOif	fLOin = 0.8 to 2.0 GHz	-23	-15	dBm		
Circuit Current at Power Save Mode	ICC(PS)	Vps = 0.5 V	0.1	0.1	μA		

10. TEST CIRCUIT

μPC2757TB, μPC2758TB



★ 11. ILLUSTRATION OF THE TEST CIRCUIT ASSEMBLED ON EVALUATION BOARD



Component List

No.	Value
C1, C2	1 000 pF
C3 to C5	3 300 pF

Notes 1. $35 \times 42 \times 0.4$ mm double sided copper clad polyimide board.

- 2. Back side: GND pattern
- 3. Solder plated on pattern
- 4. °O: Through holes

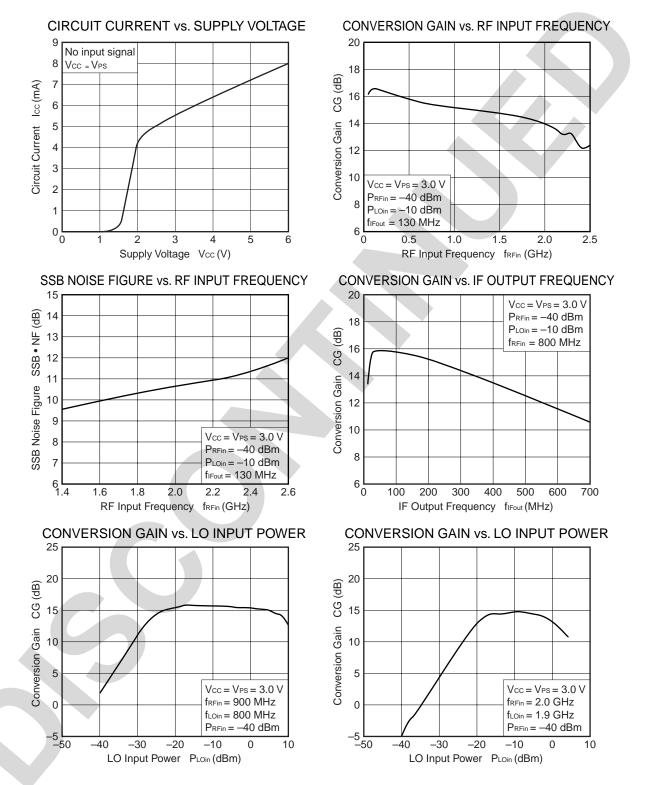
Application explanation

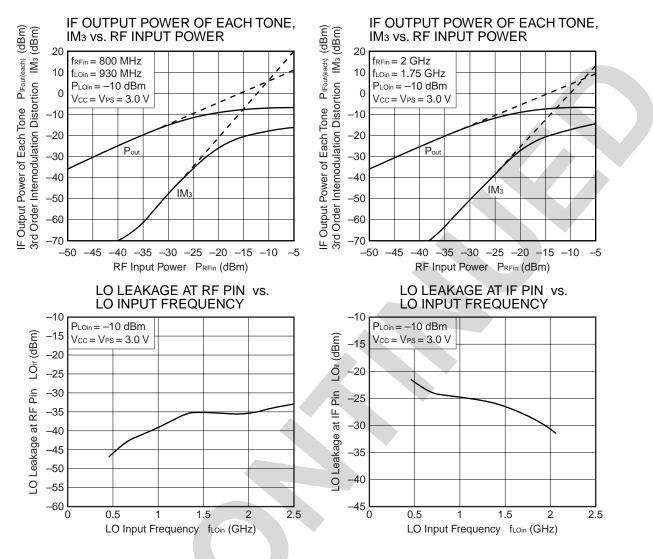
This IC is guaranteed on the test circuit constructed with 50 Ω equipment and transmission line.

This IC, however, does not have 50 Ω input/output impedance, but electrical characteristics such as conversion gain and intermodulation distortion are described herein on these conditions without impedance matching. So, you should understand that conversion gain and intermodulation distortion at input level will vary when you improve VS of RF input with external circuit (50 Ω termination or impedance matching.)

12. TYPICAL CHARACTERISTICS (TA = +25°C, on Measurement Circuit)

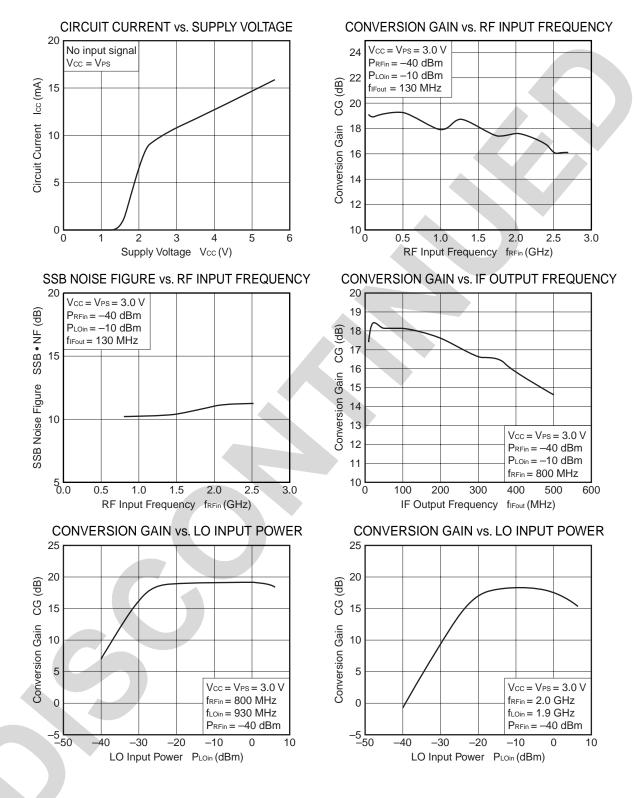
12.1 μPC2757TB

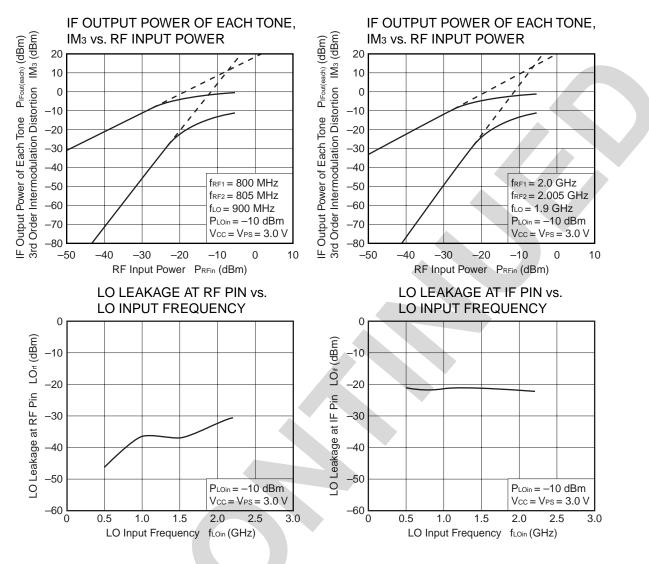




Remark The graphs indicate nominal characteristics.

12.2 µPC2758TB



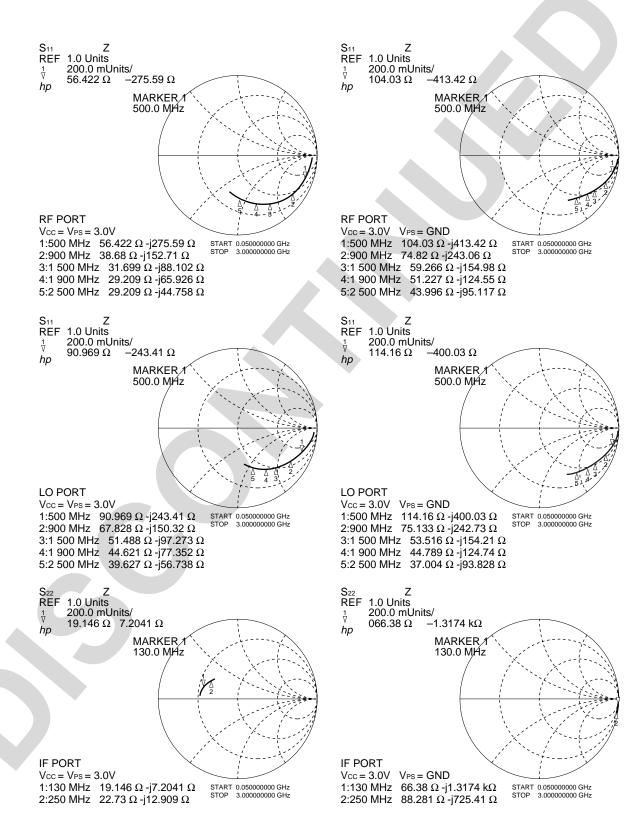


Remark The graphs indicate nominal characteristics.

13. S-PARAMETERS

13.1 μPC2757TB

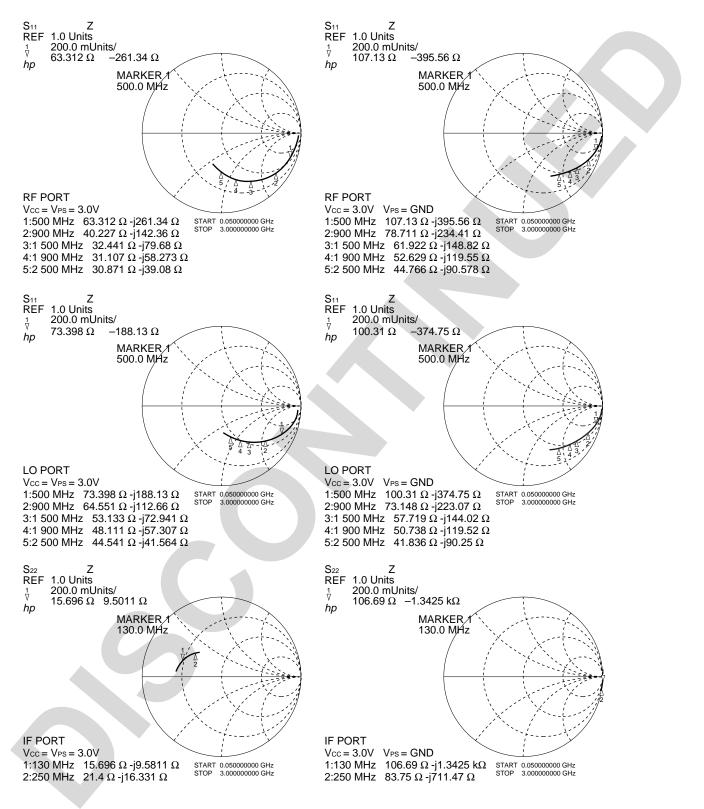
Calibrated on pin of DUT



Data Sheet P12771EJ3V0DS00

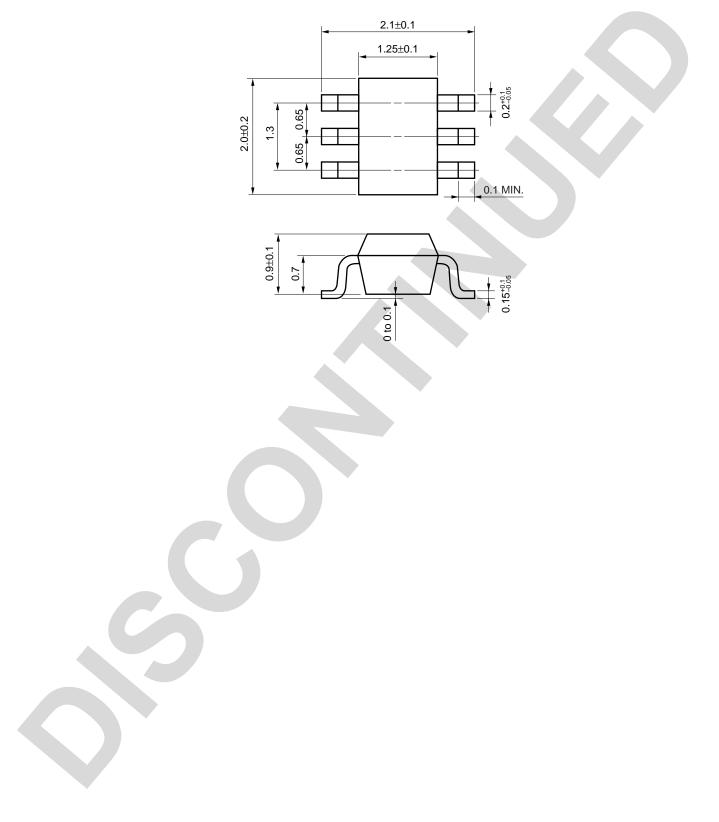
13.2 μPC2758TB

Calibrated on pin of DUT



★ 14. PACKAGE DIMENSIONS

6-PIN SUPER MINIMOLD (UNIT: mm)



15. NOTE ON CORRECT USE

- (1) Observe precautions for handling because of electrostatic sensitive devices.
- (2) Form a ground pattern as widely as possible to minimize ground impedance (to prevent undesired oscillation). Keep the track length of the ground pins as short as possible.
- (3) Connect a bypass capacitor (example: 1 000 pF) to the Vcc pin.
- (4) The DC cut capacitor must be attached to input pin.

16. RECOMMENDED SOLDERING CONDITIONS

This product should be soldered under the following recommended conditions.

Soldering Method	Soldering Condition	Recommended Condition Symbol
Infrared Reflow	Package peak temperature: 235°C or below Time: 30 seconds or less (at 210°C) Count: 3, Exposure limit: None ^{Note}	IR35-00-3
VPS	Package peak temperature: 215°C or below Time: 40 seconds or less (at 200°C) Count: 3, Exposure limit: None ^{Note}	VP15-00-3
Wave Soldering	Soldering bath temperature: 260°C or below Time: 10 seconds or less Count: 1, Exposure limit: None ^{Note}	WS60-00-1
Partial Heating	Pin temperature: 300°C Time: 3 seconds or less (per side of device) Exposure limit: None ^{Note}	_

Note After opening the dry pack, keep it in a place below 25°C and 65% RH for the allowable storage period.

Caution Do not use different soldering methods together (except for partial heating).

For details of recommended soldering conditions for surface mounting, refer to information document SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL (C10535E).

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